

A HYBRID MEMORY DEVICE

CROSS-REFERENCE

[0001] The present Application for Patent claims priority to PCT Application No. PCT/US2017/047787, entitled “Hybrid Memory Device,” filed August 21, 2017, which
5 claims priority to U.S. Patent Application No. 15/252,886 by Ryan et al., entitled “Hybrid
Memory Device,” filed August 31, 2016, each of which is assigned to the assignee
hereof, and each of which is expressly incorporated by reference in its entirety herein.

BACKGROUND

10 **[0002]** The following relates generally to memory devices and more specifically to a hybrid
memory device.

[0003] Memory devices are widely used to store information in various electronic devices
such as computers, wireless communication devices, cameras, digital displays, and the like.
Information is stored by programing different states of a memory device. For example, binary
15 devices have two states, often denoted by a logic “1” or a logic “0.” In other systems, more
than two states may be stored. To access the stored information, the electronic device may
read, or sense, the stored state in the memory device. To store information, the electronic
device may write, or program, the state in the memory device.

[0004] Various types of memory devices exist, including random access memory (RAM),
20 read only memory (ROM), dynamic RAM (DRAM), synchronous dynamic RAM (SDRAM),
ferroelectric RAM (FeRAM), magnetic RAM (MRAM), resistive RAM (RRAM), flash
memory, and others. Memory devices may be volatile or non-volatile. Non-volatile memory,
e.g., flash memory, can store data for extended periods of time even in the absence of an
external power source. Volatile memory devices, e.g., DRAM, may lose their stored state
25 over time unless they are periodically refreshed by an external power source. A binary
memory device may, for example, include a charged or discharged capacitor. A charged
capacitor may, however, become discharged over time through leakage currents, resulting in
the loss of the stored information. Certain features of volatile memory may, however, offer